Free-carrier driven spatio-temporal dynamics in amplifying silicon waveguides

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We theoretically investigate the free-carrier induced spatio-temporal dynamics of continuous waves in silicon waveguides embedded in an amplifying medium. Optical propagation is governed by a cubic Ginzburg-Landau equation coupled with an ordinary differential equation accounting for the free-carrier dynamics. We find that, owing to free-carrier dispersion, countinuous waves are modulationally unstable in both anomalous and normal dispersion regimes and chaotically generate unstable accelerating pulses.

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I. INTRODUCTION

Silicon photonics is a well established area of research aiming at exploiting silicon (Si) as a photonic component for the engineering of integrated optoelectronic devices. The extraordinary optical properties of Si open up possibilities for novel miniaturized applications, ranging from optical interconnection to bio-sensing [1, 2]. In the mid-infrared, Si has a high refractive index ($n \simeq 3.5$) and negligible linear extinction. However, in the range 1 μm $< \lambda_0 <$ 2.2 μm, two photon absorption (2PA) is relevant and is responsible for high nonlinear extinction [3]. Owing to the high refractive index, light can be tightly localized in subwavelength Si-based waveguides [5], which tremendously enhance nonlinear processes [6], including 2PA that damps optical propagation and limits the efficiency of Si-based photonic components [7]. As a consequence of 2PA, pairs of photons with total energy greater than the Si band-gap ($E_g \approx 1.12$ eV) are absorbed and electrons are excited to the conduction band modifying the Si optical response [4]. In this interesting and rather unexplored operating regime, free-carriers (FCs) directly interact with the optical field and introduce novel nonlinear effects [8]. A quite similar scenario happens in gas-filled hollow core photonic crystal fibers (HCPCFs) in the ionization regime, where accelerating solitons [9] and universal modulational instability [10] have been recently observed. In this case, the free plasma generated through ionization is responsible for an intense *blueshift* of several hundreds of nanometers of the optical pulse [11]. This tremendous dynamics occurs in a much smaller scale (blueshift of few nanometers) in Si-based waveguides [8] because of the intimate presence of 2PA, which is responsible for both the creation of FCs and for damping. In principle, losses can be reduced in hybrid slot waveguides [12], but in this case also the extraordinary effects ensuing from FC dynamics are reduced accordingly.

An alternative strategy for overcoming losses consists of embedding Si waveguides in gaining media. In this context, amplification schemes based on III-V semiconductors [13], rare-earth-ion-doped dielectric thin films [14] and erbium-doped waveguides [15] have been proposed and practically realized. The paradigm model for describing optical propagation in amplifying waveguides is represented by the cubic Ginzburg-Landau (GL) equation, which governs a wide range of dissipative phenomena [16, 17]. In general, GL systems are rich in nature and exhibit some peculiar features, e.g., chaos and pattern formation [18, 19]. Conversely to the case of conventional Kerr solitons arising from the balance between nonlinearity and dispersion [20], localized stationary solutions of GL systems - namely *dissipative solitons* - result from the exact compensation of gain and loss [21]. In a recent work, we investigated the FC-induced dynamics of dissipative solitons in Si-based amplifying waveguides, demonstrating the self-frequency soliton blueshift [22].

In this paper, we theoretically investigate the propagation of continuous waves (CWs) in a silicon-on-insulator (SOI) waveguide embedded in erbium-doped amorphous aluminium oxide (Al_2O_3:Er^+). Owing to the externally pumped active inclusions, small optical waves are exponentially amplified and instability develops until the nonlinear gain saturation comes into play counterbalancing the linear amplification. Taking full account of FC generation and recombination, we calculate the stationary nonlinear CWs of the system and we investigate their stability. We find that, analogously to gas-filled HCPCFs [10], stationary CWs are universally unstable in both normal and anomalous dispersion regimes. However, due to the inherent non-conservative nature of our system, modulational instability (MI) does not generate a shower of solitons as in Ref. [10], but an *accelerating chaotic state*. This scenario ensues from the presence of unstable dissipative solitons, which constitute the strange attractor of the system [18]. Every sub-pulse generated through MI is accelerated by the FC dispersion and experiences self-frequency blue-shift. In turn, the overall dynamics accelerates in the temporal domain and blueshifts in the frequency domain. The paper is organized as follows. In section II we describe the geometry of the system, introducing the governing equations and calculating the nonlinear stationary CW modes. In section III we analytically and numerically study MI of CWs. Analytical calculations predict universal MI and accelerating chaos, which is confirmed by numerical simulations.

II. MODEL

We consider a SOI waveguide with lateral dimensions $h = w = 525$ nm surrounded by Al_2O_3:Er^+, which gain bandwidth is of the order of 100 nm around the carrier wavelength $\lambda \simeq 1540$ nm. In principle, other gain schemes involving the use of semiconductor active materials can be considered and the gain bandwidth can be increased accordingly [23]. Without any loss of generality, we assume that the SOI waveguide is fabricated along the $[\bar{1}10]$ direction and on the $[110] \times [001]$ surface. In this case, stimulated Raman scattering (SRS) does not occur for quasi-TM modes [4]. Initially neglecting gain of the external medium, Si nonlinearity and FC generation, we have numerically calculated the linear quasi-TM mode $\mathbf{e}(\mathbf{r}_\perp)$, its dispersion $\beta_0(\omega_0)$ and the effective area by using COMSOL. At $\lambda_0 = 1550$ nm, we have then found that the second order group velocity dispersion (GVD) coefficient is $\beta_2 \simeq -2$ ps^2/m and the effective area is $A_{\rm eff} \simeq 0.145$ μm^2. Nonlinear pulse propagation can be modeled within the slowly varying envelope approximation (SVEA) by taking the Ansatz for the electric field $\mathbf{E}(\mathbf{r},t) = \mathrm{Re}\left[A(z,t)\mathbf{e}(\mathbf{r}_\perp)e^{i\beta_0 z - i\omega_0 t}\right]$, where $A(z,t)$ is the pulse envelope, $\mathbf{e}(\mathbf{r}_\perp)$ is the linear mode profile, $\omega_0 = 2\pi c/\lambda_0$ is the carrier angular frequency, c is the speed of light in vacuum and β_0 is the linear propagation constant. We approximate the external gaining medium as a two-level system, which is characterized by a Lorentzian spectral distribution of gain around the carrier angular frequency ω_0: $g(\Delta\omega) = g_0/(1 + \Delta\omega^2 T_2^2)$, where g_0 is the dimensionless gain peak, $T_2 \simeq 40$ fs is the dephasing time of Al_2O_3:Er^+ and $\Delta\omega = \omega - \omega_0$ [24]. For small detuning $\Delta\omega << \omega_0$, the spectral gain distribution can be approximated by $g(\Delta\omega) \simeq g_0 - g_2\Delta\omega^2 T_2^2$. FCs affect the optical propagation by means of two mechanisms: FC-induced dispersion (FCD) and absorption (FCA). These processes are intrinsically nonlinear and the optical propagation is governed by the coupled equations

$$i\partial_\xi u - \frac{s}{2}\partial_\tau^2 u + i\alpha u + (1 + iK)|u|^2 u \qquad (1)$$
$$-i(g_0 + g_2\partial_\tau^2)u + (i/2 - \mu)\phi_c u = 0,$$
$$\frac{d\phi_c}{d\tau} = \theta_c|u|^4 - \frac{\phi_c}{\tau_c}. \qquad (2)$$

Time duration and propagation length are normalized to the initial pulse width $t_0 = 100$ fs and dispersion length $L_{\rm D} = t_0^2/|\beta_2|$. The envelope amplitude (A) is normalized to $u = A/\sqrt{P_0}$, where $P_0 = \lambda_0 A_{\rm eff}/(2\pi n_2 L_{\rm D})$ and $n_2 \simeq (4 \pm 1.5) \times 10^{-18}$m^2/W is the Kerr nonlinear coefficient of bulk silicon [25]. In Eq. (1), the parameter $s = \pm 1$ represents the sign of the GVD ($s = +1$ normal dispersion and $s = -1$ anomalous dispersion), while the parameter $K = \beta_{\rm TPA}\lambda_0/(4\pi n_2)$ is the 2PA coefficient, where $\beta_{\rm TPA} \simeq 8 \times 10^{-12}$m/W is the bulk 2PA constant [25]. The linear loss coefficient ($\alpha_l \simeq 0.2$ dB/cm) is renormalized to the dispersion length ($\alpha = \alpha_l L_{\rm D}$) and can be neglected at $\lambda \simeq 1.55\mu$m, where 2PA dominates. The FC density (N_c) is normalized to $\phi_c = \sigma N_c L_{\rm D}$, where $\sigma \simeq 1.45 \times 10^{-21}$m^2 [26]. The parameter $\theta_c = \beta_{\rm TPA}|\beta_2|\sigma\lambda_0^3/(16\pi^3 c\hbar t_0 n_2^2)$ accounts for FCA, while $\mu = 2\pi k_c/(\sigma\lambda_0)$ accounts for FCD, where $k_c \simeq 1.35 \times 10^{-27}$m^3 [25, 27]. The characteristic FC recombination time ($t_c = 1$ ns) is also normalized to the initial pulse width: $\tau_c = t_c/t_0 = 1 \times 10^4$.

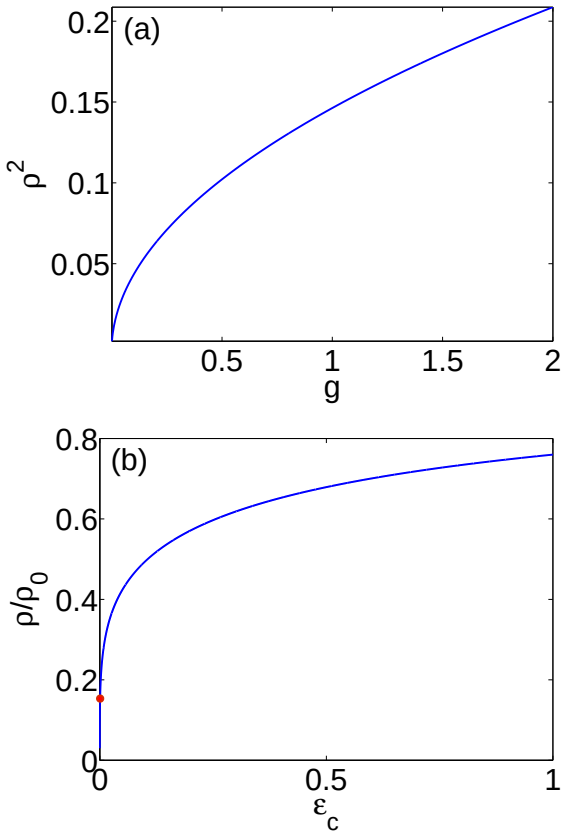

FIG. 1: (a) Squared amplitude ρ^2 of the stationary nonlinear CW mode as a function of the normalized gain parameter of the external medium g. (b) Dependence of the rescaled mode amplitude ρ/ρ_0 on the FC parameter ϵ_c for $g = 1, g_2 = 0.16$.

The stationary CW nonlinear modes of Eqs. (1,2) are found by setting the Ansatz

$$u = \rho e^{i\eta\xi}, \qquad (3)$$
$$\phi_c = \phi_0, \qquad (4)$$

where ρ, η are the mode amplitude and propagation constant, and $\phi_0 = \theta_c\tau_c\rho^4$ is the stationary number of FCs: $d\phi_c/d\tau = 0$. Inserting the Ansatz into Eqs. (1,2) one gets

$$\rho^2 = -\epsilon_c + \sqrt{\epsilon_c^2 + 2\rho_0^2\epsilon_c}, \qquad (5)$$
$$\eta = \rho^2 + 2\mu K(\rho^2 - \rho_0^2), \qquad (6)$$

where $\epsilon_c = K/(\theta_c\tau_c)$ and $\rho_0^2 = g/K$. In absence of FCs ($\epsilon_c \to \infty$), the mode amplitude ρ converges to ρ_0, which

coincides with the CW mode amplitude of the uncoupled cubic GL equation. Note that the solution above does not constitute a family, but an isolated fixed point, as it generally occurs in dissipative systems [16]. In Fig. 1a, the stationary nonlinear CW mode squared amplitude (ρ^2) is plotted against the gain parameter of the external medium (g). In Fig. 1b, the mode amplitude rescaled to the GL amplitude (ρ/ρ_0) is plotted against the FC parameter ϵ_c. Note that $\rho \to \rho_0$ in the limit where FCs are not excited ($\epsilon_c \to \infty$). The red dot in the figure indicates the exact value of ρ/ρ_0 for $g = 1, g_2 = 0.16$ and realistic parameters of Si.

III. MODULATIONAL INSTABILITY

Modulational instability (MI) of the nonlinear CW stationary mode given in Eqs. (5,6) can be determined by perturbing it with small time- and space-dependent waves:

$$u = (\rho + a)e^{i\eta\xi}, \tag{7}$$

$$\phi_c = \phi_0 + b, \tag{8}$$

where a, b are perturbations of the optical field and of the FC distribution. Plugging the Ansatz above in Eqs. (1,2) and retaining only linear terms one achieves the following set of coupled equations for a, b:

$$i\partial_\xi a = (\eta + ig)a + \left(\frac{s}{2} + ig\right)\partial_\tau^2 a + \tag{9}$$

$$-(1 + iK)\rho^2(2a + a^*) - \left(\frac{i}{2} - \mu\right)(\phi_0 a + \rho b),$$

$$\frac{db}{d\tau} = 2\theta_c\rho^3(a + a^*) - \frac{b}{\tau_c}. \tag{10}$$

We assume that $a = a_1 e^{\vartheta} + a_2^* e^{\vartheta^*}$, $b = b_0 e^{\vartheta} + b_0^* e^{\vartheta^*}$, where $\vartheta = h\xi + i\Omega\tau$, h is the growth rate of the small periodic perturbations and Ω is their angular frequency. Note that ϕ_c is real and positive, since it represents the number of FCs generated via 2PA. Inserting the expressions above for a, b in Eqs. (9,10) we achieve a set of algebraic equations for the optical field perturbations a_1, a_2:

$$\begin{bmatrix} ih + F + TL & P + TL \\ P^* + T^*L & -ih + F^* + T^*L \end{bmatrix} \begin{bmatrix} a_1 \\ a_2 \end{bmatrix} = 0, \tag{11}$$

where $P = (1 + iK)\rho^2$, $T = 2\rho^4\theta_c(i/2 - \mu)$, and

$$L = \frac{\tau_c^{-1} - i\Omega}{\tau_c^{-2} + \Omega^2}, \tag{12}$$

$$F = \left(\frac{s}{2} + ig\right)\Omega^2 + 2P - \eta - ig + \left(\frac{i}{2} - \mu\right)\phi_0 \tag{13}$$

Non-trivial solutions can be found by setting the determinant of the coefficient matrix to zero, achieving the instability eigenvalues

$$h_{1,2} = -A_0(\Omega) \pm \sqrt{A_0^2(\Omega) - B_0(\Omega)}, \tag{14}$$

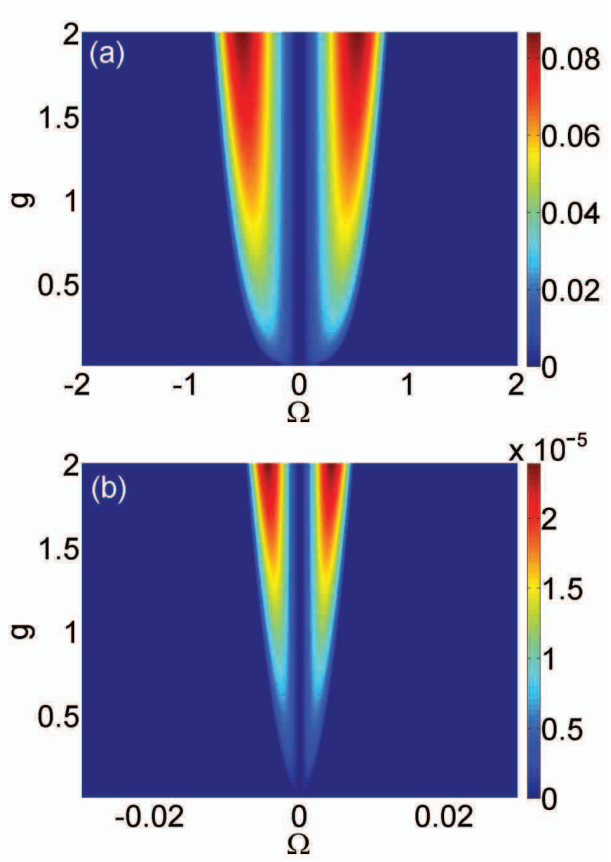

FIG. 2: Contour plots for the MI growth rate h as a function of normalized gain g and angular frequency Ω for (a) anomalous ($s = -1$) and (b) normal ($s = +1$) dispersion regimes. The second order GVD coefficient is $|\beta_2| = 2$ ps^2/m, the gain dispersion is $g_2 = 0.16$, and the 2PA coefficient is $K \simeq 0.4$.

where

$$A_0 = K\rho^2 + g_2\Omega^2 + L\theta_c\rho^4, \tag{15}$$

$$B_0 = \left(\frac{1}{4} + g_2^2\right)\Omega^4 + (2g_2K + s)\rho^2\Omega^2 + \\ +2L\theta_c(g_2 - s\mu)\rho^4\Omega^2. \tag{16}$$

If the real part of h_1 or h_2 is positive, small perturbations are amplified during propagation giving rise to instability. In Figs. 2a, 2b, we plot the instability parameter $h = \max[\mathrm{Re}h_{1,2}]$ as a function of the normalized gain g and angular frequency Ω for (a) anomalous (AD) and (b) normal (ND) dispersion. The interplay between nonlinear and dispersive effects leads to instability across the central frequency by creating sidebands. Small perturbations with angular frequencies falling within these spectral regions are amplified and eventually the nonlinear stationary CW mode breaks up into a train of pulses. Owing to the refractive index change induced by FCs, these pulses are accelerated and we found that the instability eigenvectors are asymmetrically peaked on a blue-shifted frequency. Remarkably, FC-induced instability

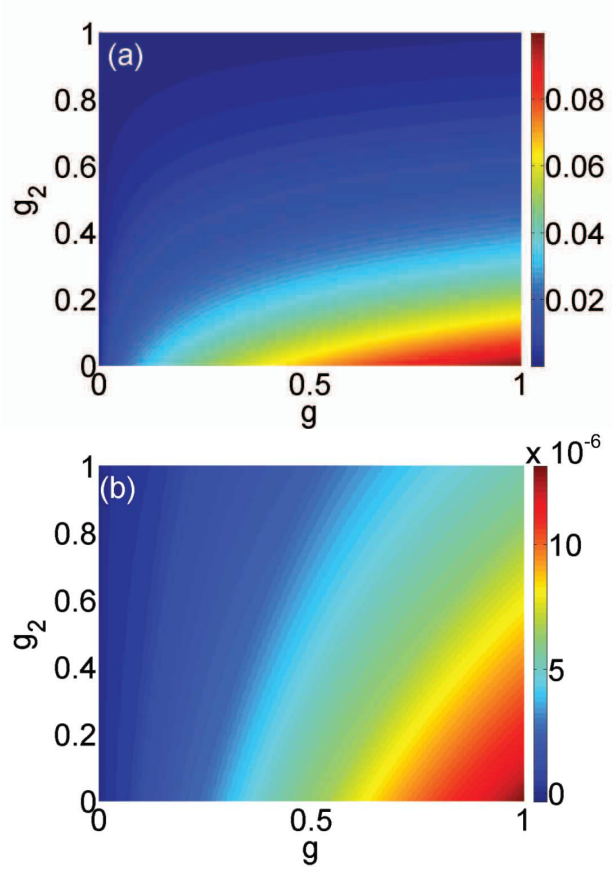

FIG. 3: Contour plot of the maximum instability eigenvalue $\max_\Omega h$ as a function of g, g_2 in (a) anomalous ($s = -1$) and (b) normal ($s = +1$) dispersion regimes. The second order GVD coefficient is $|\beta_2| = 2$ ps^2/m and the 2PA coefficient is $K \simeq 0.4$.

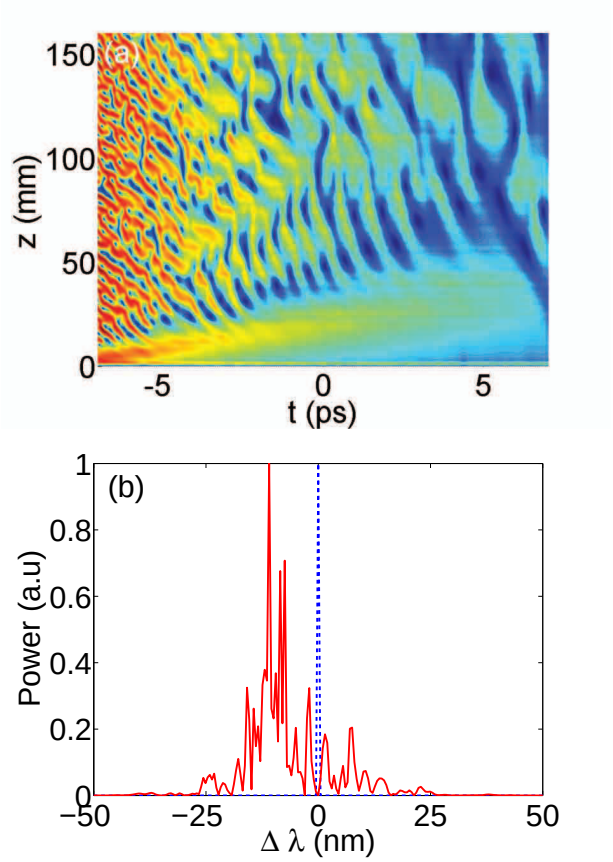

FIG. 4: (a) Accelerating chaotic state arising from the perturbed stationary CW nonlinear mode in AD. (b) Output blue-shifted spectrum (red curve) and input spectrum (dashed blue curve). In the numerical simulation we used the parameters g=1, g_2=0.16, $|\beta_2| = 2$ ps^2/m, and $K \simeq 0.4$.

can be observed in ND regime, analogously to universal plasma-induced instability observed in gas-filled hollow core photonic crystal fibers [10]. In Fig. 3 we have plotted the maximum instability eigenvalue $\max_\Omega h$ as a function of g, g_2 for (a) anomalous and (b) normal dispersion. Note that in both regimes, the instability parameter increases with gain and is reduced by gain dispersion. While in AD generation of FCs counteracts instability, in ND it is the sole crucial term responsible for its occurrence. Note that also the vacuum background is unstable in supercritical conditions ($g_0 > 0$).

In order to confirm our theoretical predictions we have numerically solved Eqs. (1,2) by using split-step fast Fourier transform and Runge Kutta algorithms. Owing to the instabilities of the vacuum and of the stationary CW modes, noise is amplified and chaotically generates unstable accelerating pulses (see Fig. 4a). Note that the intensity of the pulses is generally higher for short times and smaller for longer times. This general behavior follows from the influence of FCA, which is initially zero at $t \to -\infty$ and grows as time increases. Generation of FCs affects the pulse dynamics also via FCD, which is the sole crucial term responsible for the acceleration towards shorter times. MI continuously generates unstable dissipative solitons that play the role of the strange attractor of the chaotic system, bifurcating, collapsing and creating other pulses due to their inherent instability. The characteristic duration of the chaotically generated pulses can be analytically predicted as $\Delta\tau \simeq 2\pi|\Delta\Omega|^{-1}$, where $\Delta\Omega$ is the instability frequency window that can be calculated directly from Eq. (14). For $g = 1$ and $g_2 = 0.16$, the analytical prediction for the pulse width is $\Delta\tau \sim 1.5$ ps, which finds agreement with the numerical simulation (see Fig. 4a). The temporal acceleration of the chaotically generated pulses is accompanied in the spectral domain by a blue-shift of about 10 nm, as shown in Fig. 4b. The main obstacle hampering further blue-shifting is represented by the finite amplifying window of the gaining material. Thus, if other gaining media with larger spectral window are used, a larger blue-shift can be achieved.

IV. CONCLUSIONS

In conclusion, in this work we have investigated analytically and numerically the propagation dynamics of continuous waves in an amplifying silicon-based waveguide. We modeled optical propagation using a Ginzburg-Landau equation for the optical field coupled with a first order differential equation accounting for the generation of free-carriers. We have derived the stationary nonlinear CW mode of the system and we have studied its stability against small perturbations, finding universal modulational instability in both anomalous and normal dispersion regimes. By numerically solving the governing equations we have observed an accelerating chaotic dynamics resulting from the inherent instabilities of the system. Our theoretical investigations have been focused on a realistically accessible setup, and our theoretical predictions can be experimentally verified.

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